

L6925D

HIGH EFFICIENCY MONOLITHIC SYNCHRONOUS STEP DOWN REGULATOR

1 FEATURES

- 2.7V TO 5.5V BATTERY INPUT RANGE
- HIGH EFFICIENCY: UP TO 95%
- INTERNAL SYNCHRONOUS SWITCH
- NO EXTERNAL SCHOTTKY REQUIRED
- EXTREMELY LOW QUIESCENT CURRENT
- 800mA MAX OUTPUT CURRENT
- ADJUSTABLE OUTPUT VOLTAGE FROM 0.6V
- LOW DROP-OUT OPERATION: UP TO100% DUTY CYCLE
- SELECTABLE LOW NOISE/LOW CONSUMPTION MODE AT LIGHT LOAD
- LOW BATTERY INPUT
- LOW BATTERY OUTPUT
- ±1% OUTPUT VOLTAGE ACCURACY
- CURRENT-MODE CONTROL
- 600kHz SWITCHING FREQUENCY
- EXTERNALLY SYNCHRONIZABLE FROM 500kHz TO 1.4MHz
- OVP
- SHORT CIRCUIT PROTECTION

1.1 APPLICATIONS

- BATTERY-POWERED EQUIPMENTS
- PORTABLE INSTRUMENTS
- CELLULAR PHONES
- PDAs AND HAND HELD TERMINALS
- DSC
- GPS

Figure 2. Application Test Circuit

Figure 1. Package



Table 1. Order Codes

Part Number	Package
L6925D	MSOP8 (Tube)
L6925D013TR	Tape & Reel

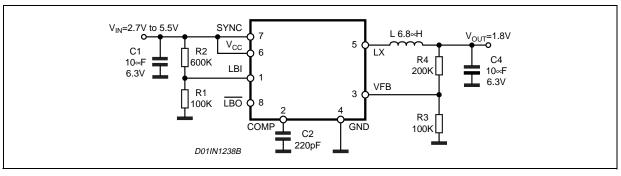
2 DESCRIPTION

The device is dc-dc monolithic regulator specifically designed to provide extremely high efficiency.

The device has on UVLO set at 2.7V cause it is particurarly thought for single Li-ion cell applications. Output voltage can be selected by an external divider down to 0.6V. Duty Cycle can saturate to 100% allowing low drop-out operation.

The device is based on a 600kHz fixed-frequency, current mode-architecture. Low Consumption Mode operation can be selected at light load conditions, allowing switching losses to be reduced. L6925D is externally synchronizable with a clock which makes it useful in noise-sensitive applications.

LBI pin can be used to have a LBO signal when the Battery voltage is lower than a preset value. Other features like, Overvoltage protection, Shortcircuit protection and Thermal Shutdown (150°C) are also present.



Symbol Value Parameter V_6 Input voltage -0.3 to 6 V_5 Output switching voltage -1 to Vcc V₁, V₈ Low Battery Input, Low Battery Output -0.3 to V_{CC} V₃ Feedback voltage -0.3 to V_{CC} V_2 Error Amplifier Output Voltage -0.3 to V_{CC} V_7 Syncronization / Mode Selector -0.3 to V_{CC} Power dissipation at Tamb=70°C Ptot 0.45 Junction operating temperature range -40 to 150 Тj Storage temperature range T_{stg} -65 to 150 LX Pin Maximum Withstanding Voltage Range Test Condition: CDF-±1000 AEC-Q100-002- "Human Body Model" Acceptance Criteria: Other pins ±2000 "Normal Performance"

Table 2. Absolute Maximum Ratings

Figure 3. Pin Connection

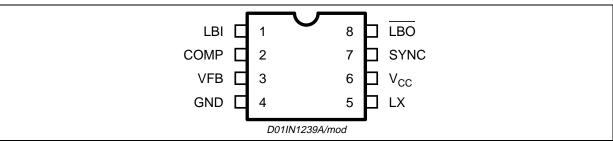


Table 3. Thermal Data

Symbol	Parameter	Value	Unit
R _{th j-amb}	Thermal Resistance Junction to Ambient	180	°C/W

Table 4. Pin Functions

Ν	Name	Description					
1	LBI	Battery low voltage detector input. The internal threshold is set to 0.6V. The external threshold can be adjusted by using an external resistor divider.					
2	COMP	Error amplifier output. Compensate it with a 220pF capacitor					
3	VFB	Error amplifier input. The output voltage can be adjusted by using an external resistor divider connected to this pin ($V_{FB} = 0.6V$).					
4	GND	Ground.					
5	LX	Switch node connection to the inductor.					
6	VCC	Input voltage.					
7	SYNC	This pin allows to select Low Noise/ Low Consumption Mode or to sychronize the device.					
8	LBO	Battery low voltage detector output. If the voltage at the LBI pin drops below the internal thrshold, LBO goes low. The LBO is an open drain output. A pull_up resistor should be connected between the pin and the output voltage					

Unit

V

V V

V

V

V

W

°C

°C

V

V

Symbol	Parameter	Test Condition	Min	Тур	Max 5.5	Unit
V _{cc}	Operating input voltage	After Turn On	2.7			V
V _{cc ON}	Turn On threshold			2.8		V
V_{ccOFF}	Turn Off threshold			2.65		V
V _{cc hys}	Hysteresis			150		mV
Rp	High side Ron	V _{cc} = 3.6V, I _{lx} =100mA		240		mΩ
R _n	Low side Ron	$V_{cc} = 3.6V, I_{lx} = 100mA$		215		mΩ
l _{lim}	Peak current limit	V _{cc} = 3.6V		1.2		А
	Valley current limit	V _{cc} = 3.6V		1.4		А
Vout	Output voltage range		0.6		Vcc	V
f _{osc}	Oscillator frequency			600		KHz
f _{sync}	Sync mode clock (*)		500		1400	KHz
DC CHARA	CTERISTICS	1	1		1 1	
Ιq	Quiescent current (low noise mode)	$V_{sync} = 0V$, no load, $V_{FB} > 0.6V$		230		∝A
	Quiescent current (low cunsumption mode)	$V_{sync} = V_{cc}$, no load, $V_{FB} > 0.6V$		25		∝A
I _{sh}	Shutdown current	V _{cc} < 2.7V, V _{FB} > 0.6V		0.2		∝A
I _{IX}	LX leakage current (*)	V_{cc} < 2.7V, V_{LX} = V_{cc}		1		∝A
		$V_{cc} < 2.7 V, V_{LX} = 0 V$		1		∝A
ERROR AM	PLIFIER CHARACTERISTICS				1	
V _{fb}	Voltage feedback		0.593	0.6	0.607	V
I _{fb}	Feedback input current (*)	V _{FB} = 0.6V		25		nA
SYNC/MOD	E FUNCTION				II	
V _{sync_H}	Sync mode threshold high				1.3	V
V _{sync_L}	Sync mode threshold low		0.5			V
LB SECTIO	N	I			1	
V _{LBI}	LBI Threshold			0.6		V
V _{LBO}	LBO Logic Low	$I_{sink} = 1mA, V_{cc} = 3.6V, \\ V_{LBI} < 0.6V$		0.2	0.4	V
I _{LK-LBO}	LBO Leakage Current (*)	$V_{\overline{LBO}} = 3.6V, V_{CC} = 3.6V, V_{LBI} > 0.6V$			50	nA
PROTECTIO	DNS	I			1	
HOVP	Hard overvoltage threshold			10		%Vou

Table 5. ELECTRICAL CHARACTERISTICS (T_J = 25° C, V_{CC} = 3.6V unless otherwise specified)

(*) Guaranteed by design

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Figure 4. MSOP8 Mechanical Data & Package Dimensions

DIM.	mm			inch			
DIIVI.	MIN.	TYP.	MAX.	MIN.	TYP.	MAX.	OUTLINE AND MECHANICAL DATA
А			1.10			0.043	
A1	0.050		0.150	0.002		0.006	
A2	0.750	0.850	0.950	0.03	0.033	0.037	
b	0.250		0.400	0.010		0.016	
С	0.130		0.230	0.005		0.009	20
D (1)	2.900	3.000	3.100	0.114	0.118	0.122	SSSS
Е	4.650	4.900	5.150	0.183	0.193	0.20	e
E1 (1)	2.900	3.000	3.100	0.114	0.118	0.122	
е		0.650			0.026		
L	0.400	0.550	0.700	0.016	0.022	0.028	
L1		0.950			0.037		
k		C	[°] (min.)	6° (max	.)		
aaa			0.100			0.004	MSOP8
PI	N 1 IDE	NTIFICATI			5	E	SEATING PLANE C C C C C C C C C C C C C C C C C C C

Table 6. Revision History

Date	Revision	Description of Changes
January 2004 2		First Issue in EDOCS DMS
September 2004 3		Changed Style-sheet and Table 2

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